# 查询"CPH6412"供应商



N-Channel Silicon MOSFET

# **CPH6412**

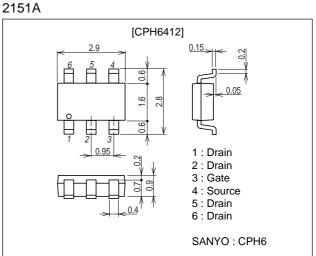
# **Ultrahigh-Speed Switching Applications**

# Features

- Low ON-resistance.
- · Ultrahigh-speed switching.
- 4V drive.

# **Package Dimensions**

unit : mm



# **Specifications**

### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	۱D		6	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	24	А
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm <sup>2</sup> X0.8mm)	1.6	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

### Electrical Characteristics at Ta=25°C

Symbol	Conditions	Ratings			Linit
		min	typ	max	Unit
V(BR)DSS	ID=1mA, VGS=0	30			V
IDSS	VDS=30V, VGS=0			1	μA
IGSS	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0			±10	μA
VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.2		2.6	V
yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =3A	4.2	6		S
R <sub>DS</sub> (on)1	ID=3A, VGS=10V		25	33	mΩ
R <sub>DS</sub> (on)2	ID=1.5A, VGS=4.5V		35	49	mΩ
RDS(on)3	ID=1.5A, VGS=4V		37	52	mΩ
	V(BR)DSS IDSS IGSS VGS(off)  yfs  RDS(on)1 RDS(on)2	V(BR)DSS  ID=1mA, VGS=0    IDSS  VDS=30V, VGS=0    IGSS  VGS=±16V, VDS=0    VGS(off)  VDS=10V, ID=1mA     yfs   VDS=10V, ID=3A    RDS(on)1  ID=3A, VGS=10V    RDS(on)2  ID=1.5A, VGS=4.5V	V(BR)DSS  ID=1mA, VGS=0  30    IDSS  VDS=30V, VGS=0  1000000000000000000000000000000000000	Symbol  Conditions  min  typ    V(BR)DSS  ID=1mA, VGS=0  30     IDSS  VDS=30V, VGS=0	Symbol  Conditions  min  typ  max    V(BR)DSS  ID=1mA, VGS=0  30  1  1    IDSS  VDS=30V, VGS=0  30  1  1    IGSS  VGS=±16V, VDS=0  1  ±10    VGS(off)  VDS=10V, ID=1mA  1.2  2.6     yfs   VDS=10V, ID=3A  4.2  6    RDS(on)1  ID=3A, VGS=10V  25  33    RDS(on)2  ID=1.5A, VGS=4.5V  35  49

Marking : KN

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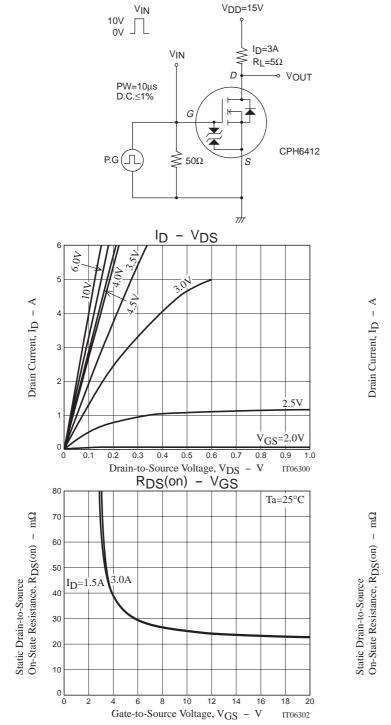
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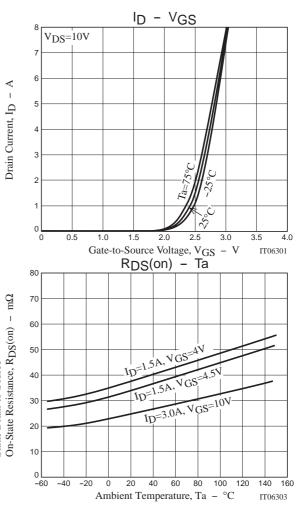
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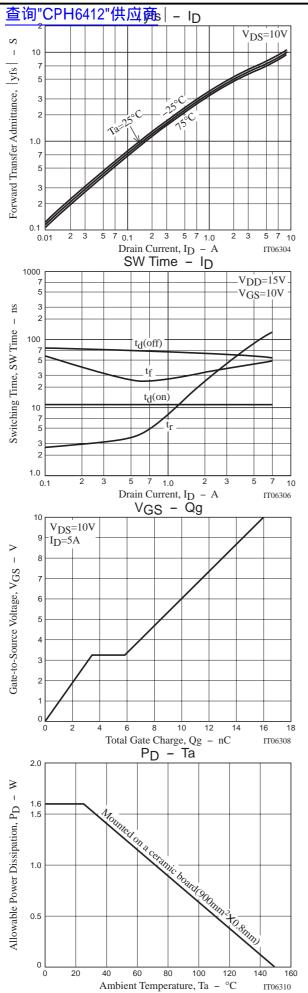
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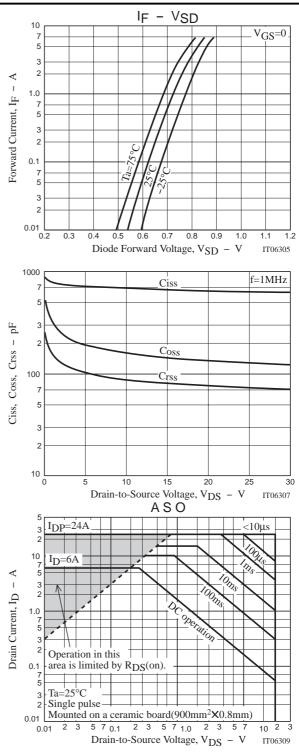
Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Input Capacitance	Ciss	V <sub>DS</sub> =10V, f=1MHz		690		pF
Output Capacitance	Coss	V <sub>DS</sub> =10V, f=1MHz		160		pF
Reverse Transfer Capacitance	Crss	VDS=10V, f=1MHz		88		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		11		ns
Rise Time	tr	See specified Test Circuit.		45		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		60		ns
Fall Time	tf	See specified Test Circuit.		35		ns
Total Gate Charge	Qg	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =5A		16		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =5A		3.4		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =5A		2.4		nC
Diode Forward Voltage	VSD	IS=6A, VGS=0		0.84	1.2	V

## Switching Time Test Circuit









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